# Triple Schmitt-Trigger Inverter

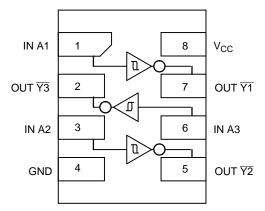
The NLX3G14 MiniGate<sup>™</sup> is an advanced high–speed CMOS triple Schmitt–trigger inverter in ultra–small footprint.

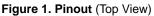
The NLX3G14 input and output structures provide protection when voltages up to 7.0 V are applied, regardless of the supply voltage.

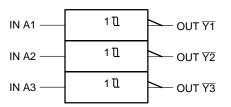
The NLX3G14 can be used to enhance noise immunity or to square up slowly changing waveforms.

# Features

- Designed for 1.65 V to 5.5 V  $V_{CC}$  Operation
- Low Power Dissipation:  $I_{CC} = 1 \ \mu A$  (Max) at  $T_A = 25^{\circ}C$
- 24 Balanced Output Source and Sink Capability
- Balanced Propagation Delays
- Overvoltage Tolerant (OVT) Input and Output Pins
- Ultra-Small Packages
- These are Pb–Free Devices







## Figure 2. Logic Symbol

FUNCTION TABLE				
Α	Ÿ			
L	н			
Н	L			

### PIN ASSIGNMENT

1	IN A1
2	OUT ¥3
3	IN A2
4	GND
5	OUT ₹2
6	IN A3
7	OUT Y1
8	V <sub>CC</sub>



# **ON Semiconductor®**

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		MARKING DIAGRAMS
	UDFN8 1.45 x 1.0 CASE 517BZ	2 M 1 <b>o</b>
	UDFN8 1.6 x 1.0 CASE 517BY	1 <b>o</b>
	UDFN8 1.95 x 1.0 CASE 517CA	1 • X M
F, AC M ■	, 2 = Specific Devic = Date Code = Pb–Free Pacl	

## **ORDERING INFORMATION**

See detailed ordering and shipping information in the package dimensions section on page 5 of this data sheet.

# MAXIMUM RATINGS

Symbol	Parameter	Value	Unit
V <sub>CC</sub>	DC Supply Voltage	-0.5 to +7.0	V
V <sub>IN</sub>	DC Input Voltage	-0.5 to +7.0	V
V <sub>OUT</sub>	DC Output Voltage	-0.5 to +7.0	V
I <sub>IK</sub>	DC Input Diode Current V <sub>IN</sub> < GND	-50	mA
I <sub>OK</sub>	DC Output Diode Current V <sub>OUT</sub> < GND	±50	mA
Ι <sub>Ο</sub>	DC Output Source/Sink Current	±50	mA
I <sub>CC</sub>	DC Supply Current Per Supply Pin	±100	mA
I <sub>GND</sub>	DC Ground Current per Ground Pin	±100	mA
T <sub>STG</sub>	Storage Temperature Range	-65 to +150	°C
ΤL	Lead Temperature, 1 mm from Case for 10 Seconds	260	°C
TJ	Junction Temperature Under Bias	150	°C
MSL	Moisture Sensitivity	Level 1	
F <sub>R</sub>	Flammability Rating Oxygen Index: 28 to 34	UL 94 V–0 @ 0.125 in	
V <sub>ESD</sub>	ESD Withstand Voltage Human Body Model (Note 2) Machine Model (Note 3) Charged Device Model (Note 4)	> 2000 > 200 N/A	V
ILATCHUP	Latchup Performance Above $V_{CC}$ and Below GND at 125°C (Note 5)	±500	mA

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected. 1. Measured with minimum pad spacing on an FR4 board, using 10 mm-by-1 inch, 2 ounce copper trace no air flow.

2. Tested to EIA / JESD22-A114-A.

3. Tested to EIA / JESD22-A115-A.

4. Tested to JESD22-C101-A.

5. Tested to EIA / JESD78.

## **RECOMMENDED OPERATING CONDITIONS**

Symbol	Parameter			Max	Unit
V <sub>CC</sub>	Positive DC Supply Voltage		1.65	5.5	V
V <sub>IN</sub>	Digital Input Voltage		0	5.5	V
V <sub>OUT</sub>	Output Voltage		0	5.5	V
T <sub>A</sub>	Operating Free–Air Temperature		-55	+125	°C
Δt/ΔV	Input Transition Rise or Fall Rate	$V_{CC} = 2.5 V \pm 0.2 V V_{CC} = 3.3 V \pm 0.3 V V_{CC} = 5.0 V \pm 0.5 V$	0 0 0	No Limit No Limit No Limit	ns/V

Functional operation above the stresses listed in the Recommended Operating Ranges is not implied. Extended exposure to stresses beyond the Recommended Operating Ranges limits may affect device reliability.

# DC ELECTRICAL CHARACTERISTICS

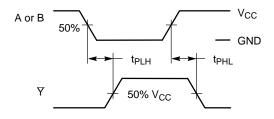
			V <sub>CC</sub>		T <sub>A</sub> = 25 °C		T <sub>A</sub> = +85°C		T <sub>A</sub> = −55°C to +125°C		
Symbol	Parameter	Conditions	(V)	Min	Тур	Max	Min	Max	Min	Max	Unit
V <sub>T+</sub>	Positive Threshold Voltage		1.65 2.3 2.7 3.0 3.0 4.5	0.6 1.0 1.2 1.3 1.9 2.2	1.0 1.5 1.7 1.9 2.7 3.3	1.4 1.8 2.0 2.2 3.1 3.6	0.6 1.0 1.2 1.3 1.9 2.2	1.4 1.8 2.0 2.2 3.1 3.6	0.6 1.0 1.2 1.3 1.9 2.2	1.4 1.8 2.0 2.2 3.1 3.6	V
V <sub>T-</sub>	Negative Threshold Voltage		1.65 2.3 2.7 3.0 3.0 4.5	0.2 0.4 0.5 0.6 1.0 1.2	0.5 0.75 0.87 1.0 1.5 1.9	0.8 1.15 1.4 1.5 2.0 2.3	0.2 0.4 0.5 0.6 1.0 1.2	0.8 1.15 1.4 1.5 2.0 2.3	0.2 0.4 0.5 0.6 1.0 1.2	0.8 1.15 1.4 1.5 2.0 2.3	V
V <sub>H</sub>	Hysteresis Voltage		1.65 2.3 2.7 3.0 3.0 4.5	0.1 0.25 0.3 0.4 0.6 0.7	0.48 0.75 0.83 0.93 1.2 1.4	0.9 1.1 1.15 1.2 1.5 1.7	0.1 0.25 0.3 0.4 0.6 0.7	0.9 1.1 1.15 1.2 1.5 1.7	0.1 0.25 0.3 0.4 0.6 0.7	0.9 1.1 1.15 1.2 1.5 1.7	V
V <sub>OH</sub>	High–Level	$V_{IN} \le V_{T-MIN}$ $I_{OH} = -100 \ \mu A$	1.65 to 5.5	V <sub>CC</sub> – 0.1	V <sub>CC</sub>		V <sub>CC</sub> – 0.1		V <sub>CC</sub> – 0.1		V
	Output Voltage	$\begin{array}{l} V_{IN} \leq V_{T-MIN} \\ I_{OH} = -4 \mbox{ mA} \\ I_{OH} = -8 \mbox{ mA} \\ I_{OH} = -12 \mbox{ mA} \\ I_{OH} = -16 \mbox{ mA} \\ I_{OH} = -24 \mbox{ mA} \\ I_{OH} = -32 \mbox{ mA} \end{array}$	1.65 2.3 2.7 3.0 3.0 4.5	1.29 1.9 2.2 2.4 2.3 3.8	1.52 2.1 2.4 2.7 2.5 4.0		1.29 1.9 2.2 2.4 2.3 3.8		1.29 1.8 2.1 2.3 2.2 3.7		
V <sub>OL</sub>	Maximum Low–Level Output	$\begin{array}{l} V_{IN} \geq V_{T+MAX} \\ I_{OL} = 100 \ \mu A \end{array}$	1.65 to 5.5		0	0.1		0.1		0.1	V
	Voltage	$\begin{array}{l} V_{IN} \geq V_{T+MAX} \\ I_{OH} = 4 \mbox{ mA} \\ I_{OH} = 8 \mbox{ mA} \\ I_{OH} = 12 \mbox{ mA} \\ I_{OH} = 16 \mbox{ mA} \\ I_{OH} = 24 \mbox{ mA} \\ I_{OH} = 32 \mbox{ mA} \end{array}$	1.65 2.3 2.7 3.0 3.0 4.5		0.08 0.2 0.22 0.28 0.38 0.42	0.24 0.3 0.4 0.4 0.55 0.55		0.24 0.3 0.4 0.4 0.55 0.55		0.24 0.4 0.5 0.5 0.55 0.65	
I <sub>IN</sub>	Input Leakage Current	$0 \le V_{IN} \le 5.5 V$	0 to 5.5			±0.1		±1.0		±1.0	μΑ
I <sub>OFF</sub>	Power–Off Output Leakage Current	V <sub>OUT</sub> = 5.5 V	0			1.0		10		10	μΑ
I <sub>CC</sub>	Quiescent Supply Current	$0 \le V_{IN} \le V_{CC}$	5.5			1.0		10		10	μΑ

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

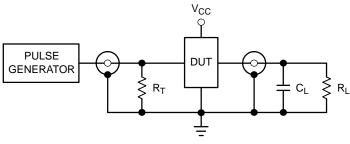
		V <sub>CC</sub>	Test	т		c	<b>TA</b> = -	⊦85°C	T <sub>A</sub> = - to +1	-55°C 25°C	
Symbol	Parameter	(V)	Condition	Min	Тур	Max	Min	Max	Min	Max	Unit
t <sub>PLH</sub> , t <sub>PHL</sub>	Propagation Delay, Input A to Output Y	2.3–2.7	$\begin{array}{l} R_L = 1 \; M\Omega, \\ C_L = 15 \; pF \end{array}$	1.8	4.3	7.4	1.8	8.1	1.8	9.1	ns
		3.0–3.6	$\begin{array}{l} R_L = 1 \; M\Omega, \\ C_L = 15 \; pF \end{array}$	1.5	3.3	5.0	1.5	5.5	1.5	6.5	
			$R_L = 500 \Omega,$ $C_L = 50 pF$	1.8	4.0	6.0	1.8	6.6	1.8	7.6	
		4.5–5.5	$R_L = 1 M\Omega,$ $C_L = 15 pF$	1.0	2.7	4.1	1.0	4.5	1.0	5.5	
			$R_L = 500 \Omega,$ $C_L = 50 pF$	1.2	3.2	4.9	1.2	5.4	1.2	6.4	
C <sub>IN</sub>	Input Capacitance	5.5	V <sub>IN</sub> = 0 V or V <sub>CC</sub>		2.5						pF
C <sub>PD</sub>	Power Dissipation Capacitance (Note 6)	3.3 5.5	10 MHz V <sub>IN</sub> = 0 V or V <sub>CC</sub>		11 12.5						pF

# AC ELECTRICAL CHARACTERISTICS (Input $t_r = t_f = 3.0 \text{ ns}$ )

6. C<sub>PD</sub> is defined as the value of the internal equivalent capacitance which is calculated from the dynamic operating current consumption without load. Average operating current can be obtained by the equation I<sub>CC(OPR)</sub> = C<sub>PD</sub> • V<sub>CC</sub> • f<sub>in</sub> + I<sub>CC</sub>. C<sub>PD</sub> is used to determine the no–load dynamic power consumption: P<sub>D</sub> = C<sub>PD</sub> • V<sub>CC</sub><sup>2</sup> • f<sub>in</sub> + I<sub>CC</sub> • V<sub>CC</sub>.



# Figure 3. Switching Waveforms



 $R_T = Z_{OUT}$  of pulse generator (typically 50  $\Omega$ )

Figure 4. Test Circuit

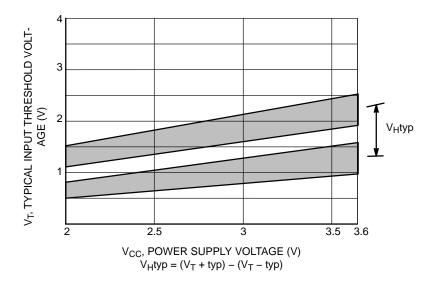
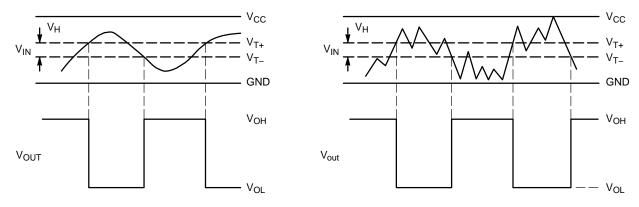


Figure 5. Typical Input Threshold, V<sub>T</sub>+, V<sub>T</sub>-versus Power Supply Voltage



(a) A Schmitt-Trigger Squares Up Inputs With Slow Rise and Fall Times

(b) A Schmitt-Trigger Offers Maximum Noise Immunity

# Figure 6. Typical Schmitt–Trigger Applications

## **ORDERING INFORMATION**

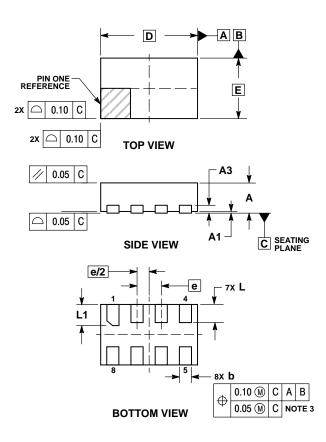
Device	Package	Shipping <sup>†</sup>
NLX3G14DMUTCG (In Development)	UDFN8, 1.95 x 1.0, 0.5P (Pb–Free)	3000 / Tape & Reel
NLX3G14EMUTCG (In Development)	UDFN8, 1.6 x 1.0, 0.4P (Pb–Free)	3000 / Tape & Reel
NLX3G14FMUTCG	UDFN8, 1.45 x 1.0, 0.35P (Pb–Free)	3000 / Tape & Reel

+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

# NLX3G14

# PACKAGE DIMENSIONS

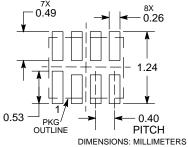
UDFN8 1.6x1.0, 0.4P CASE 517BY ISSUE O



- NOTES:
  1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
  2. CONTROLLING DIMENSION: MILLIMETERS.
  3. DIMENSION b APPLIES TO PLATED TERMINAL AND IS MEASURED BETWEEN 0.15 AND 0.20 MM FROM TERMINAL TIP.
  4. PACKAGE DIMENSIONS EXCLUSIVE OF BURRS AND MOLD FLASH.

BURRS AND MOLD FI					
	MILLIN	MILLIMETERS			
DIM	MIN	MAX			
Α	0.45	0.55			
A1	0.00	0.05			
A3	0.13 REF				
b	0.15	0.25			
D	1.60	BSC			
Е	1.00	BSC			
е	0.40	0.40 BSC			
L	0.25	0.35			
L1	0.30	0.40			

## RECOMMENDED **SOLDERING FOOTPRINT\***

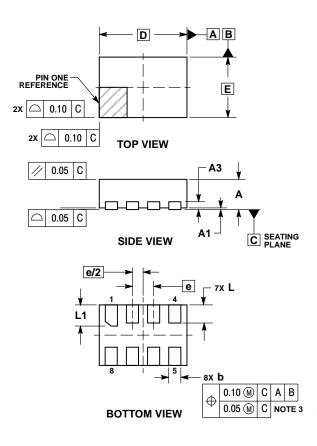


\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

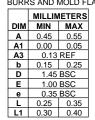
# NLX3G14

# PACKAGE DIMENSIONS

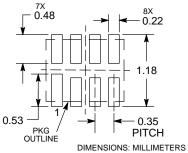
UDFN8 1.45x1.0, 0.35P CASE 517BZ ISSUE O



- NOTES:
  DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
  CONTROLLING DIMENSION: MILLIMETERS.
  DIMENSION & APPLIES TO PLATED TERMINAL AND IS MEASURED BETWEEN 0.15 AND 0.20 MM FROM TERMINAL TIP.
  PACKAGE DIMENSIONS EXCLUSIVE OF BURRS AND MOLD FLASH.



# RECOMMENDED SOLDERING FOOTPRINT\*

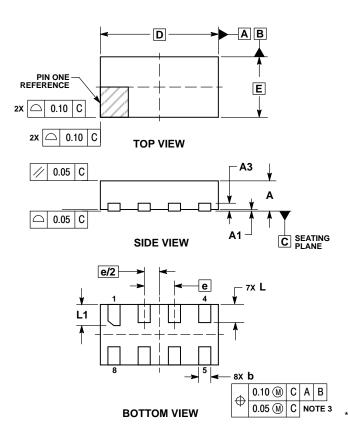


\*For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

# NLX3G14

### PACKAGE DIMENSIONS

UDFN8 1.95x1.0, 0.5P CASE 517CA ISSUE O

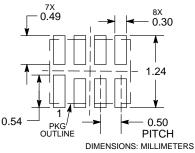


NOTES: 1. DIMENSIONING AND TOLERANCING PER

- ASME Y14.5M, 1994. 2. CONTROLLING DIMENSION: MILLIMETERS.
- 3. DIMENSION b APPLIES TO PLATED TERMINAL AND IS MEASURED BETWEEN
- 0.15 AND 0.20 MM FROM TERMINAL TIP. 4. PACKAGE DIMENSIONS EXCLUSIVE OF BURRS AND MOLD FLASH.

BORRO AND MOLD I						
	MILLIN	MILLIMETERS				
DIM	MIN	MAX				
Α	0.45	0.55				
A1	0.00	0.05				
A3	0.13 REF					
b	0.15	0.25				
D	1.95 BSC					
Е	1.00 BSC					
е	0.50	0.50 BSC				
L	0.25	0.35				
L1	0.30	0.40				

### RECOMMENDED SOLDERING FOOTPRINT\*



\*For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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